


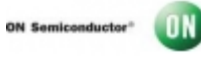
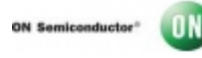



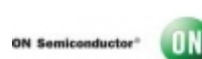

	<h2 style="color: red;">BS107ARL1G</h2>
	<p><b>Hersteller-Teilenummer:</b> BS107ARL1G</p> <p><b>Hersteller / Marke:</b> AMI Semiconductor / ON Semiconductor</p> <p><b>Teil der Beschreibung:</b> MOSFET N-CH 200V 0.25A TO-92</p> <p><b>Datenblätter:</b>  <a href="#">BS107ARL1G.pdf</a></p> <p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p> <p><b>Lagerzustand:</b> New original, 6585 pcs Stock Available.</p> <p><b>Liefern von:</b> Hong Kong</p> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

### Spezifikationen

Teilenummer	BS107ARL1G
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 200V 0.25A TO-92
Kategorie	<a href="#">Diskrete Halbleiterprodukte &gt; Transistoren-FETs,</a>
Teilstatus	6585 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-226-3, TO-92-3 (TO-226AA) (Formed Leads)
Supplier Device-Gehäuse	TO-92-3
Verlustleistung (max)	350mW (Ta)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	200V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	250mA (Ta)
Rds On (Max) @ Id, Vgs	6.4 Ohm @ 250mA, 10V
VGS (th) (Max) @ Id	3V @ 1mA
Gate Charge (Qg) (Max) @ Vgs	-
Eingabekapazität (Ciss) (Max) @ Vds	60pF @ 25V
Verpackung	Tape & Reel (TR)

BS107ARL1G ist neu im Original, Suche BS107ARL1G Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie BS107ARL1G AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage BS107ARL1G: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 <p><b>BS107P</b> Diodes Incorporated MOSFET N-CH 200V 120MA TO92-3</p>	 <p><b>BS107A</b> AMI Semiconductor / ON Semiconductor BS107A ON</p>	 <p><b>BS107G</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 200V 0.25A TO- 92</p>	 <p><b>BS107</b> INFINEO BS107 INFINEO</p>
 <p><b>BS107PSTOB</b> Diodes Incorporated MOSFET N-CH 200V 0.12A TO92-3</p>	 <p><b>BS107PSTOA</b> Diodes Incorporated MOSFET N-CH 200V 0.12A TO92-3</p>	 <p><b>BS107AG</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 200V 0.25A TO- 92</p>	 <p><b>BS1016EM13-24</b> Altech Corporation MARKINGPLATE15MMPITCH MARKED 13</p>

### heiße Teile

Mehr

04023A180GAT2A	04025A430KAT2A	6MBI150SA-060CB	D 70HAR120	91MT80KB
A104K15X7RF5UAA	AA05E-024L-120D	D AD1985JST-REEL	AD7769JP	BS107KL-T1-E3
BS108ZL1G	BS120E0F	BS170FTA	BS170RLRAG	BS1800N-C
D BZM55C6V8-TR	BZX384B47-V-GS08	C1005X5R1A154K050BC	CL05B393K05NNNC	CL21B103KBNC
CL31B104MBCNNNC	CL31B153KHFSFNE	CSACW40M0X51-R0	DS1834AS+	GRM1885C1H152GA01D
GRM21BR72A683KAC4L	HD14044BP	D IRL014TRPBF	IRS2608DS	ISL6612ACRZ-T
LT3513EUHF#TRPBF	LTC1531CSW	MMD7N02ZR2G	NVB6412ANT4G	PM75LFE120
RT9202BPS	SFH6742-X007T	SG3526DW	Si2318CDS-T1-E3	SN74BCT25245DWR
SP724AHTG	SS12P2LHM3/86A	SY88289ALMI	D TAR5SB50	TLC2252CPW
TMC57486TB52	VI-2M-MY	WPD26-14	XC61CC2902PR	YFF18PH0J105MT009N

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